JUN 16 2006 B

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THE ANSMITTAL OF FORMAL DRAWINGS

Docket No. FIS920030412US1

In Re Application Of: Marwan H. Khater, et al.

Application No. Filing Date Examiner Customer No. Group Art Unit Confirmation No. 10/709,220 04/22/2004 Michelle Estrada 32,074 2826 3219

Invention: STRUCTURE AND METHOD OF FORMING BIPOLAR TRANSISTOR HAVING A SELF-ALIGNED RAISED EXTRINSIC BASE USING SELF-ALIGNED ETCH STOP LAYER

Address to:

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Transmitted herewith are:

12 sheets of formal drawing(s) for this application.

Each sheet of drawing indicates the identifying indicia suggested in 37 CFR Section 1.84(c).

Hoavel Skurrians

Dated: May 11, 2006

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I hereby certify that this correspondence is being deposited with the United States Postal Service with sufficient postage as first class mail in an envelope addressed to "Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450" [37 CFR 1.8(a)] on

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